EXHIBIT 2

Express Mail No.:

EV023687891 US

Mailed:

January 21, 7005 James A. Cooper, et al.

Applicant: Invention:

Optimized Vertical Power DMOSFETS

in Silicon Carbide

Serial No.:

Unknown

Filed:

Herewithin

Docket:

64281.P1.US

X Provisional Application Transmittal
X Provisional Application (7 pages)

The stamp of the Patent Office hereon shows receipt of the indicated papers.

CAH

PTO/SB/16 (08-03)

Approved for use through 07/31/2006. OMB 0651-0032

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PROVISIONAL APPLICATION FOR PATENT COVER SHEET

This is a request for filing a PROVISIONAL APPLICATION FOR PATENT under 37 CFR 1.53(c).

Express Mail Label No. EV 023687891 US

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INVENTOR(S) Clina Name (first and middle life and a Fermille Name or Surname Pacidosea (City and either State or Foreign Country)							
			Family Name or Surname		Residence (City and either State or Foreign Country)		
· · · · · · · · · · · · · · · · · · ·		Cooper, Jr.	r, Jr.		West Lafayette, Indiana		
Asmita Saha Saha		L		West Lafayette, Indiana separately numbered sheets attached hereto			
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ENCLOSED A	PPLICATION PARTS	check all that	apply)				
Specification Nu	mber of Pages7	CD(s), Nur	mber				į
Drawing(s) <i>Numi</i>	her of Sheets	Other (s	pecify)				
	Sheet, See 37 CFR 1.7						
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	YMENT OF FILING FE		JVISIONAL AI	PPLICATION			·
Applicant claims small entity status. See 37 CFR 1.27.							
A check or money order is enclosed to cover the filing fees. X The Director is herby authorized to charge filing							
fees or credit any overpayment to Deposit Account Number: 502939							
Payment by credit card. Form PTO-2038 is attached.							
The invention was made by an agency of the United States Government or under a contract with an agency of the United States Government.							
X No.							
Yes, the name of the U.S. Government agency and the Government contract number are:							
[Page 1 of 1]							
Respectfully submitted, Date January 21, 2005							
SIGNATURE COMPLETE REGISTRATION NO. (15 appropriate)							
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Docket Number: 64281.P1.US

TYPED or PRINTED NAME James A. Cooper, Jr.

TELEPHONE __765-496-7712

USE ONLY FOR FILING A PROVISIONAL APPLICATION FOR PATENT

This collection of information is required by 37 CFR 1.51. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 8 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. **SEND TO: Mail** Stop Provisional Application, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2.

OFFICE OF TECHNOLOGY COMMERCIALIZATION

DIVISION OF RESEARCH & SCHOLARLY ACTIVITIES
PURDUE RESEARCH FOUNDATION - PURDUE UNIVERSITY

64281

INVENTION RECORD AND DISCLOSURE CONFIDENTIAL

NOTE: This form requires the signatures of: Department Head(s) and School Dean(s). Please complete the attached form and then route to Department Head(s), Dean(s) and then back to the Office of Technology Commercialization (OTC), 1291 Cumberland Avenue, Suite F, West Lafayette, IN 47906 (Note: Please feel free to add additional attachments to elaborate on any questions, or to call the Office of Technology Commercialization at 42610 for assistance).

I. Formal Record of Disclosure

Please identify by name, phone number, department and building, each individual who contributed to development of the proposed invention <u>and</u> who will share in any net proceeds from the proposed invention. Please note that individuals listed here <u>may or may not</u> qualify as legal inventors for patent applications. Type the name and campus address of your department (school) head and school dean and <u>obtain signatures</u>.

A. Disclosure Title: Op	TIMIZED VERTICAL	POWER DMOSFETS IN	SILICON CARBIDE
B. Disclosure Date: 12	-19-04		
C. Full legal names (including mid- legal name.	dle name) and titles of inventor/	submitter(s) (Please print: Prof/Dr/M	Ir/Ms, followed by full
Title Name (ALBERT PROF. JAMES A. COOPE		Department ECE è BNC	Building
MS. ASMITA SAHA	494 - 3706	ECE È BNC	EE EE
D. Disclosure must be reviewed an Department Head(s) MARK J.T. SMITH, E Comments:	Signature /	artment Head and Dean	Date 01/03/05
Dean(s) of School	Signature Alfu	J. Martin	<u>Date</u> 01/07/05
Comments:	-		

CONFIDENTIAL

PU0000003

II. Sponsorship

Please specify the source of funds that were used in the research that led to the technology, including contract number from which salaries and other project costs were paid, which resulted in the disclosure. This information is critical for correct identification of sponsors and meeting obligations to them.

NODO14-02-1-0628

A. Government Agency/Address: DARPA/MTO 3701 NORTH FAIRFAX DRIVE HULLALOH! MY 93303-1214

Contract/Grant #: DEVELOPMENT OF PROCESS Grant/Contract Title: TECHNOLOGIES FOR HIGH-

PERFORMANCE MUS-BASED

B. Name of department, industry, foundation or other

sponsor/Address:

Contract/Grant#: Grant/Contract Title:

SIC POWER SWITCHING DEVICES

C. Has the invention been disclosed to industry representatives? If "yes" please provide details, including names of companies and their representatives and dates: No

III. Publications, Public Use and Sale

Please be as thorough as possible, giving the exact date and place each event occurred. Valid patent protection depends on accurate answers to the following items.

- A. Dates, Places of the invention, and other pertinent data:
 - 1. Conception: JAN-APRIL 2004
 - 2. First Sketch or APRIL 34, 2004

Drawing:

- 3. First Written Description: APRIL 31, 2004
- 4. Model or Full Size Device, if any: } NONE YET
- 5. First Test or Operation, if

any:

6. First Public Disclosure (and circumstances); Public disclosure is defined as oral or written information made available to the public in such a manner that said information can be understood by one skilled in the art:

NONE YET

B. Has proposed invention been disclosed in an abstract, paper, talk, news story or thesis? If "yes," please enclose drafts, abstracts, preprints.

Type of disclosure:

NO

Disclosure Date:

C. Is a publication, poster, thesis or other disclosure planned? When? If "yes," please enclose drafts, abstracts, preprints.

Type of disclosure:

YES

Anticipated Date:

THESIS: SEDT. 2005

D. Has there been any public use or sale of products embodying the proposed invention? If yes, please describe, giving dates.

Description:

No

Date:

E. Are you aware of related developments by others? If "yes," please give citations. Copies of any relevant Patents/Publications would be appreciated. YES: OUR OWN WORK HAS LAID THE GROUNDWORK FOR Citations:

THIS INVENTION, ONE EARLIER PATENT

F. List any closely related publications, patents, or patent applications of others which are known to you. Publications. Publication/Patent Information: PURDLE 1975-T APPLICATION; P-01104,00 (4-9-04 FILING)
PVBLICATION: M. MATIN, A. SAHA, & J.A. COOPER, IEEE TRANS. ON ELECTRON DEVICES, VOL. 51, PR 1721-1725 (2004)

G. Do you currently have plans to make the disclosed material available to others? (YES) If YES, please briefly describe the procedures you would follow to accomplish this:

THIS WORK WILL BE PRESENTED DARPA PROGRAM REVIEWS AT

IV. Detailed Description of the Invention

Please attach a detailed description of the invention. This description can be in the form of a manuscript, publication(s) or other written documents. This description <u>should</u> allow one skilled in the art to practice the proposed invention.

SEE PP. 51-52 OF PATENT HOTEBOOK (ATTACHED)

SEE ALGO! PHD THESIS PROPOSAL OF ASMITA SAHA, SCHOOL OF

ELECTRICAL AND COMPUTER ENGINEERING, JULY 17, 2004.

V. Witness and Understand the Detailed Description of the Invention Disclosure

The undersigned witnesses have read and understood the detailed description for the above described invention disclosure.

SEE P. S. OF PATENT NOTEBOOK (ATTACHED)

	,	
Witness Signature	Typed/Printed Name	Date
Witness Signature	Typed/Printed Name	Date

VI. Disposition of Royalties and Attestation

Each inventor should sign the attestation and indicate the agreed upon percentage of the inventor's share which should be awarded to each inventor.

The undersigned hereby attest(s) that the foregoing information is true and accurate.

I (We) agree with the provisions of Executive Memorandum B-10 and Business Office Memorandum 170. I (We) specifically recognize that the Committee on Patents and Copyrights shall as a general principle, but subject to all relevant provisions of Executive Memorandum B-10, award a two-third interest to the University and a one-third interest to the inventor/submitter(s) or creator(s) of the net proceeds derived from Inventions and Materials belonging to the University. I (We) hereby agree to divide said one-third interest in the proportions hereinafter specified before each signature below.

<u>50</u>	Signature (Inventor/Submitter)	12-19-04 Date
<u>50</u> %	Asuril Signature (Inventor/Submitter)	12-20-04 Date
%	Signature (Inventor/Submitter)	Date
%	Signature (Inventor/Submitter)	Date

Please Note: If this disclosure is sent to a patent attorney for review, copies of the following information may be required:

- 1. Copy of references
- 2. Copy of early notebook pages
- 3. Copy of first written description of proposed invention
- 4. Copy of first test/operation of proposed invention

VII. Marketing Information

Please complete the following section thoroughly. Provide as much information as possible as it will be used to assess commercial potential and provide information to potential licensees.

- A. Disclosure Title: OPTIMIZED VERTICAL POWER DMOSFETS IN SILICON CARBIDE
- B. Description of Invention (Please emphasize the benefits of the invention)
- C. Why is this technology better than present technology?

SEE PP. 51-52 (ATTACHED)

- D. What are its novel and unusual features?
- E. What problems does the technology solve?
- F. How were those problems solved in the past?
- G. What company or companies are interested in the technology or are the major supplier(s) of similar technology

CREE, INC. NORTHRUP-GRUMMAY RUCKWELL GENERAL ELECTRIC

H. Describe briefly what will be required to complete the development of the invention before commercialization.

Estimated Cost:

DEVICE FABRICATION IS UNDERWAY, AND DEMONSTRATION DEVICES SHOULD BE COMPLETED BY 30 JUNE 2005. WORK IS FUNDED BY DARRA / MTO.

VIII. Marketing Summary of the Invention (Non-confidential/Non-Technical Information)

Please summarize the invention in terms such that its value can be understood by a potential licensee. This summary will be used for distribution to companies to determine commercial interest in the proposed invention. Please provide a one <u>paragraph</u> concise description. This summary <u>must not</u> allow one skilled in the art to practice the proposed invention.

a structure and method of fobilication of vertical DMOS power transistars in silicon carbide to achieve close to the minimum theoretical on-state resistance at a given blocking voltage.

IX. Technology Classification

Please classify the disclosed technology in as many of the following areas that you believe apply to the technology.

LIFE SCIENCE / BIOTECHNOLOGY	INFORMATION SCIENCE
Animals	Computer Hardware (Specify)
Biomedical (Specify)	Mainframe
Diagnostic	UNIX
Therapeutic	☐ PC
Dental	Computer Software
Foods and Nutrition	Telecommunications
Health Sciences	Other (Specify)
Medical Devices (Specify)	
Diagnostic	EDUCATIONAL MATERIAL
Therapeutic	Printed and/or Artwork Material
Pharmaceutical (Specify)	Software
Diagnostic	Videos
Therapeutic	Multimedia
Plants	Other (Specify)
Other (Specify)	OTHER (Specify)
PHYSICAL SCIENCE	
Automotive Engineering	
Chemical Science/Chemical Engineering	
Construction, related	
∑ Electronics	
Energy	
Fluid Mechanics	
Manufacturing	
Materials	
Mechanical Engineering/Devices	
Separations	
Transportation	
Waste Treatment	
Other (Specify)	

